

XT3409



GaAs MMIC Digital Attenuator
DC~13GHz

Rev 1.2

Features

- Frequency: DC~13GHz
- Insertion Loss: -2dB
- Positive Voltage Control
- Die Size: 1.38mm×1.21mm×0.1mm

Typical Applications

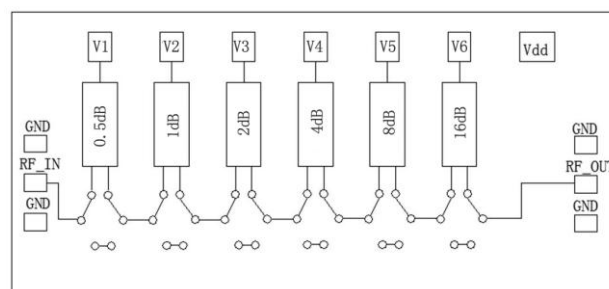
- EW
- Cellular Infrastructure
- SATCOM
- Beamforming Modules
- Test Equipment and Sensors

General Description

XT3409 is a broadband 6-bit GaAs digital attenuator MMIC chip. Covering DC to 13GHz, the insertion loss is less than 3.2 dB typically. The attenuator bit values are 0.5dB, 1dB, 2dB, 4dB, 8dB and 16dB for a total attenuation of 31.5dB. Three TTL 0/-5V inputs are used to select each attenuation state.

The chip offers full passivation for increased reliability and moisture protection.

Functional Diagram



Electrical Performance ($T_A=+25^{\circ}\text{C}$, $V_d=-5\text{V}$, Control Voltage=0/-5V, $Z_0=50\Omega$)

Parameter	Min.	Typ.	Max.	Units
Frequency	DC~13			GHz
Input Return Loss	—	-18	—	:1
Output Return Loss	—	-18	—	:1
Insertion Loss	—	-2	—	dB
A_{TT} -Phase Error	—	20	—	°

Truth Table (0 : 0V, 1 : -5V)

Attenuation	V1	V2	V3	V4	V5	V6
REF	0	0	0	0	0	0
0.5dB	1	0	0	0	0	0
1dB	0	1	0	0	0	0
2dB	0	0	1	0	0	0
4dB	0	0	0	1	0	0
8dB	0	0	0	0	1	0
16dB	0	0	0	0	0	1
31.5dB	1	1	1	1	1	1

XT3409



GaAs MMIC Digital Attenuator
DC~13GHz

Rev 1.2

Control Voltage

State	Bias
Low	0~-0.5V
High	-4.5~-5.5V

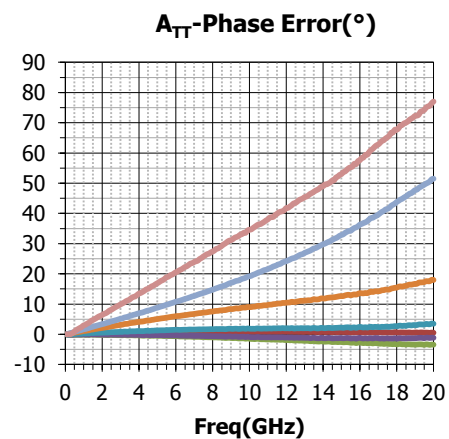
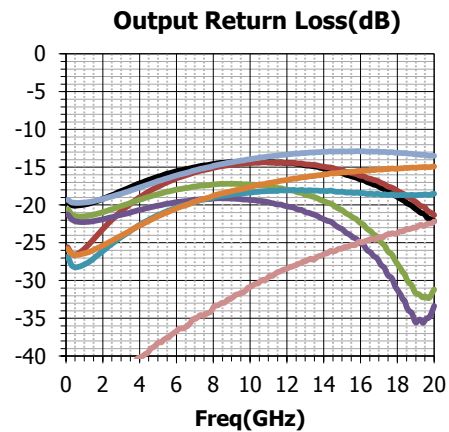
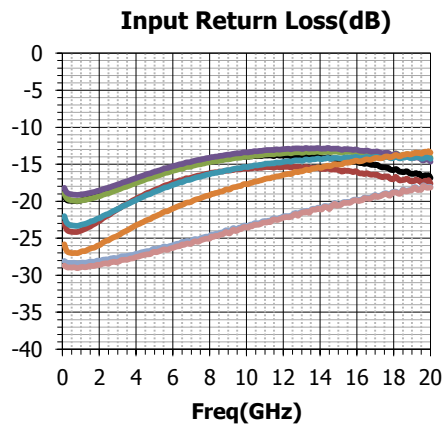
Absolute Maximum Ratings

Maximum Input Power	Maximum Input Voltage
+23dBm	-8V
Operating Temperature	Storage Temperature
-55°C ~ +85°C	-65°C ~ +150°C

Power Supply

V _D	I _D
-5V	4mA

Typical Performance Curve

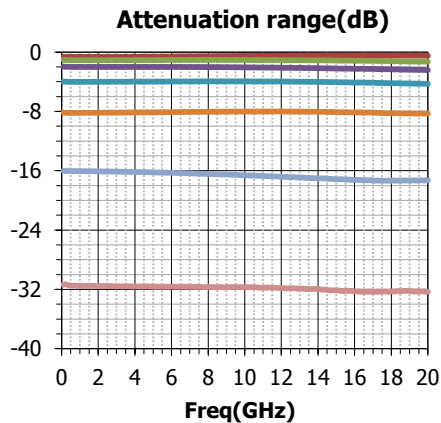


XT3409

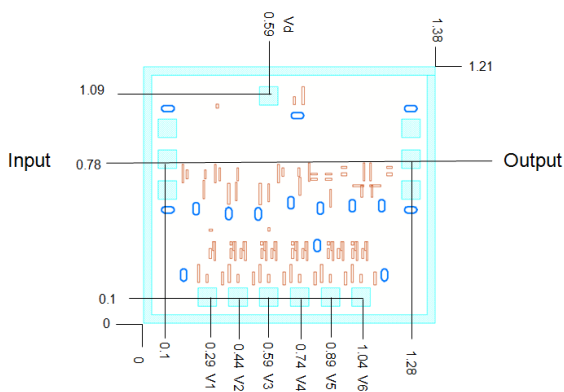


GaAs MMIC Digital Attenuator
DC~13GHz

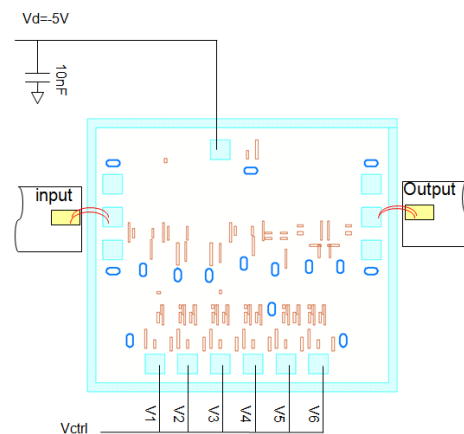
Rev 1.2



Die Outline
(all dimensions in mm)



Assembly Diagram



Attention:

GaAs MMIC devices are susceptible to damage from electrostatic discharge. Proper precautions should be observed during handling, assembly and test.